

# Thoughts on Future Silicon Detectors

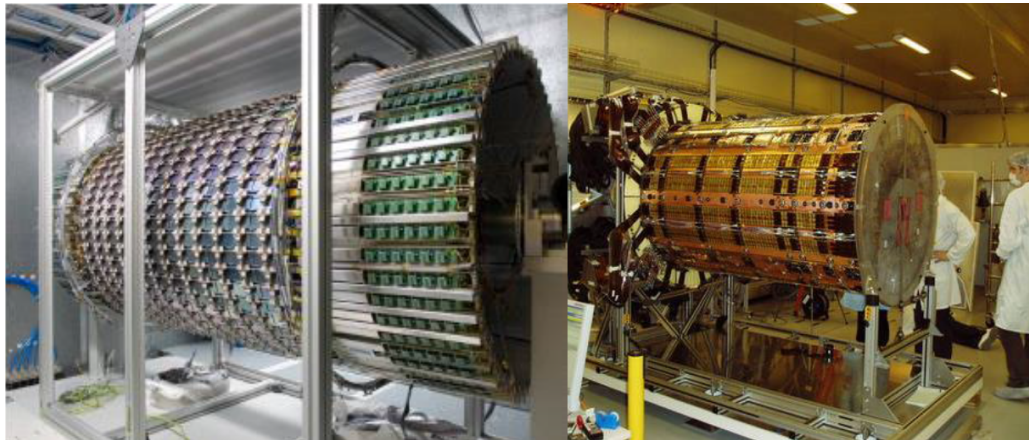
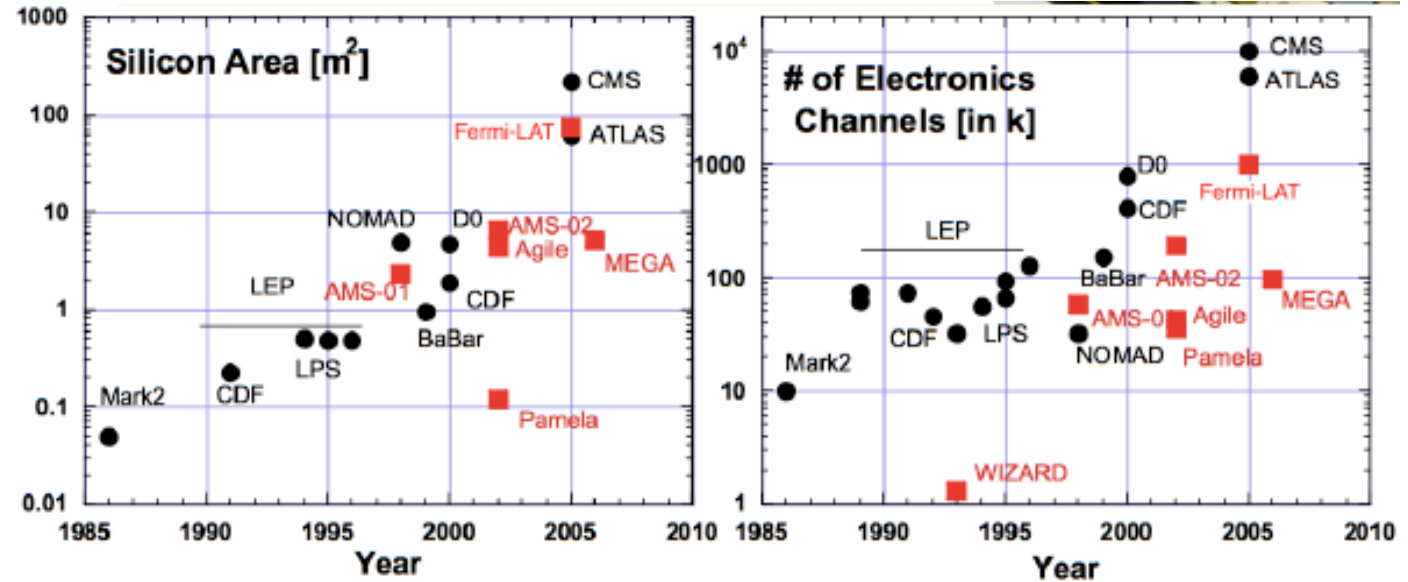
Jessica Metcalfe

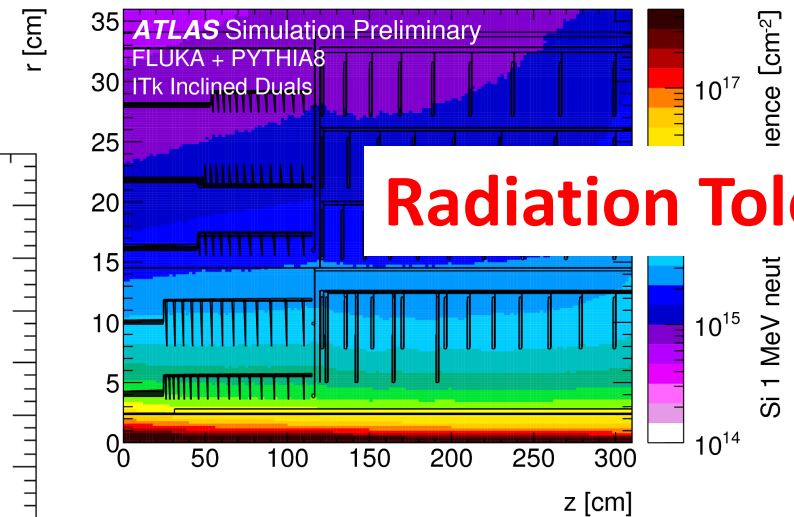
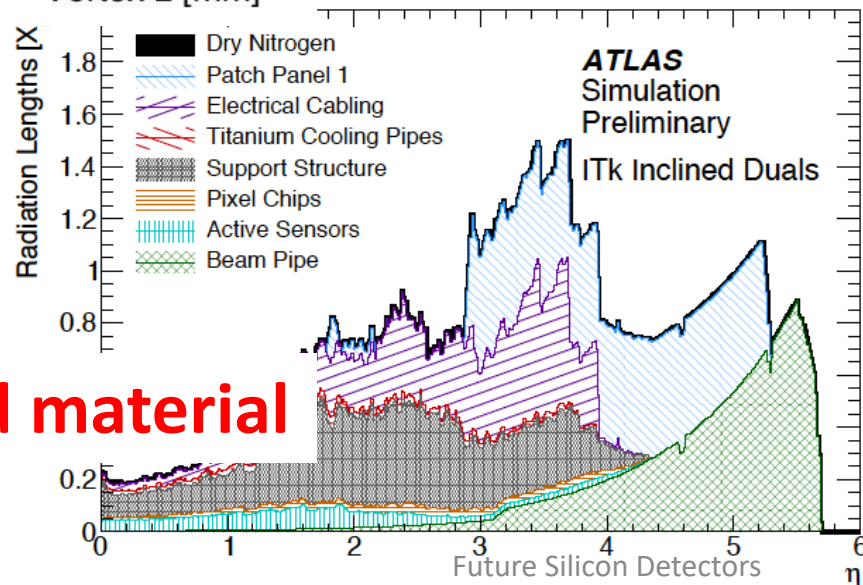
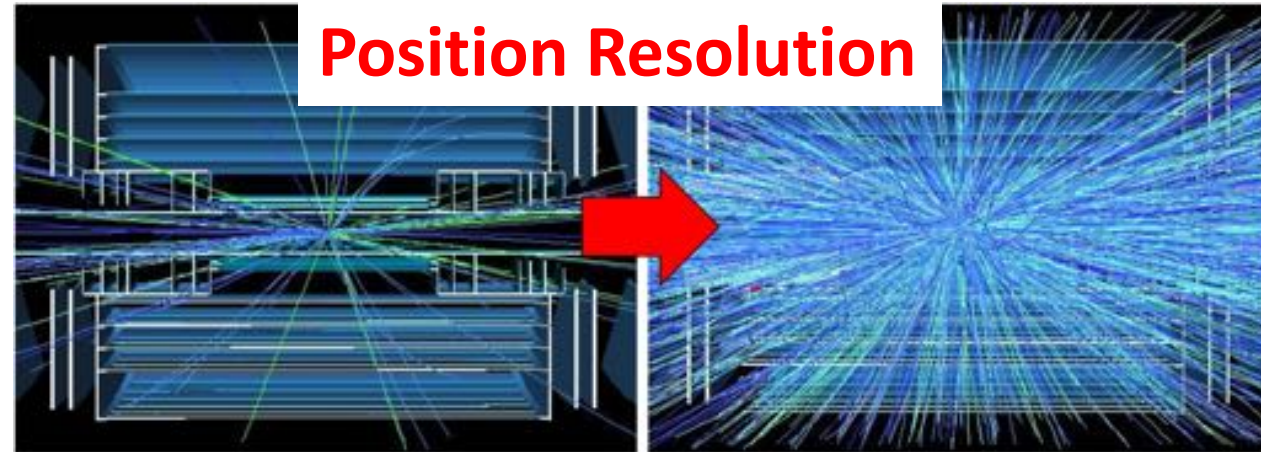
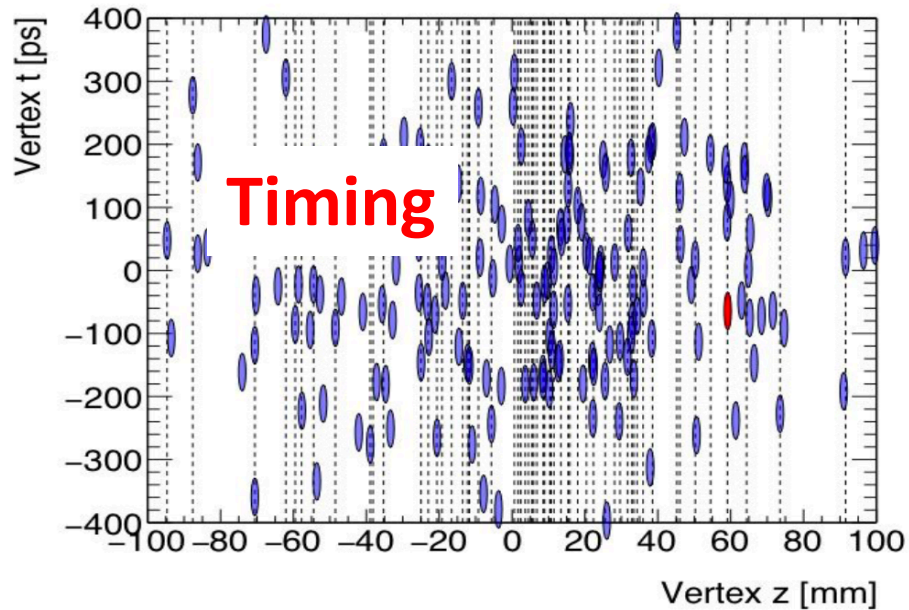
# Motivation

Silicon detectors are a cornerstone of High Energy Physics

Larger fractions of detectors are made with silicon

- Limiting factor is often the cost
- More layers for precise tracking
- shift toward high precision silicon calorimeters
- no reason not to make the entire detector out of silicon other than cost





**Low mass/dead material**

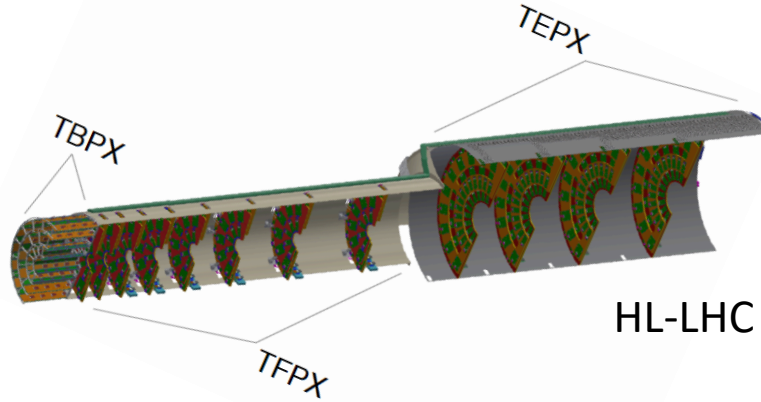
**Radiation Tolerance**

...Typical of large accelerator experiments

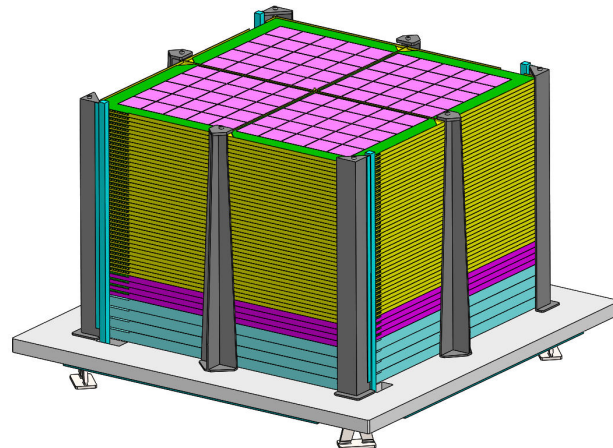
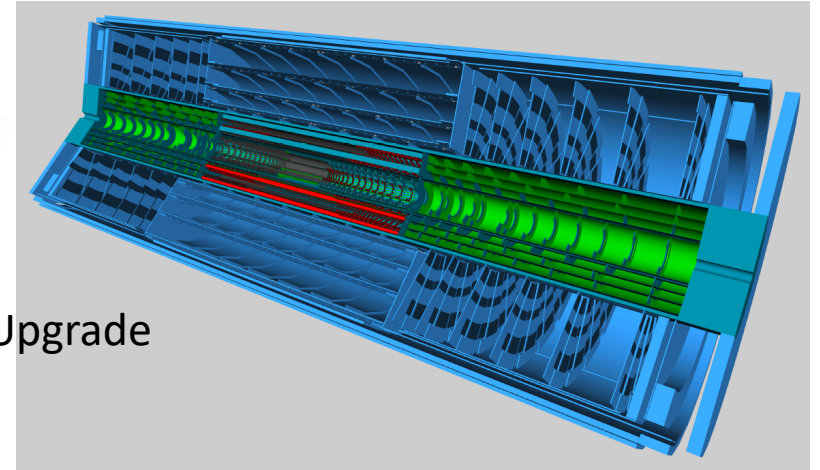
# Synergies

Work with other upcoming experiments

- Electron ion collider
- Neutrinoless double beta decay
- Gamma-ray telescopes in space
- ....

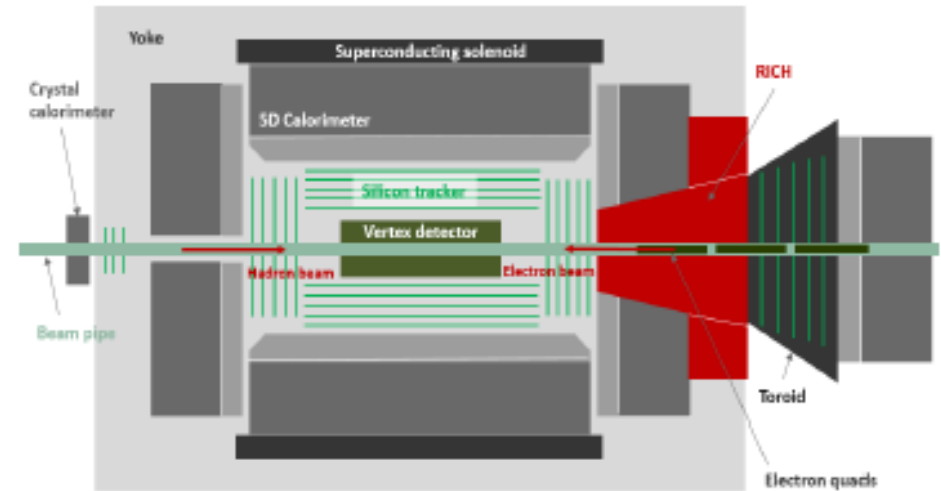


HL-LHC Upgrade



AMEGO

## EIC: TOPSiDE concept



- **Low Mass**
  - **Low power**
  - **High position resolution**
  - **Fast timing resolution**
  - **Monolithic**
  - **Radiation Tolerance**
  
  - **Energy resolution**
  - **Energy range: signal/noise**
    - **Low electron energies**
- **Low cost**
  
  - **Reduce services**
  - **Reduce cooling needs**
  
  - **All-in-one?**
    - **Fewer 'sub-systems'**
      - **Reduce cost**
      - **Optimize resources**
  
  - **Faster development cycle**

**How many features can we combine into one detector technology?**

# Current Snapshot

## Existing Sensor Technologies

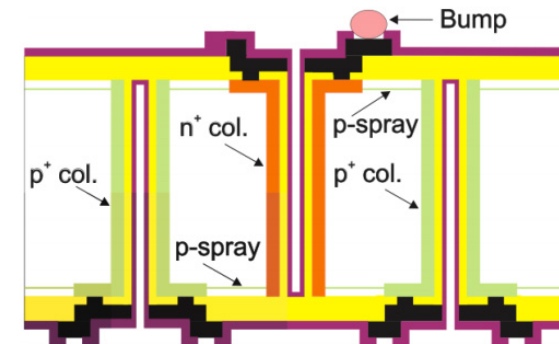
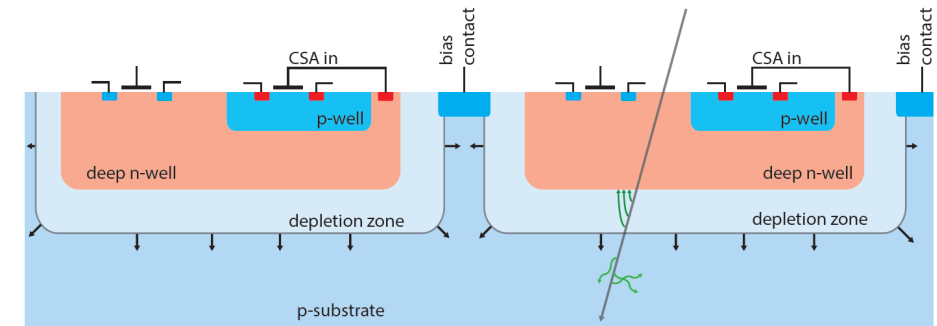
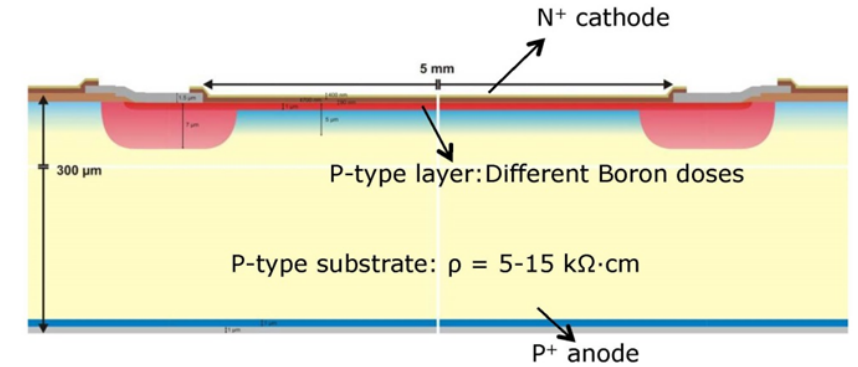
- LGAD's (presented last time) –pad sizes: mm, cm
  - AC LGAD's ~10  $\mu\text{m}$  pixels
- Monolithic detectors
  - MAPS (diffusion), slow
  - Monolithic CMOS (SiGe) (drift)
  - ns collection times HL-LHC
  - Low power/low mass (low occupancy)
- Diamond detectors
- 3D sensors

## New technologies that could combine multiple features

- => monolithic LGAD's?
- Thin Film Detectors?
- Low power electronics

## Not silicon but...

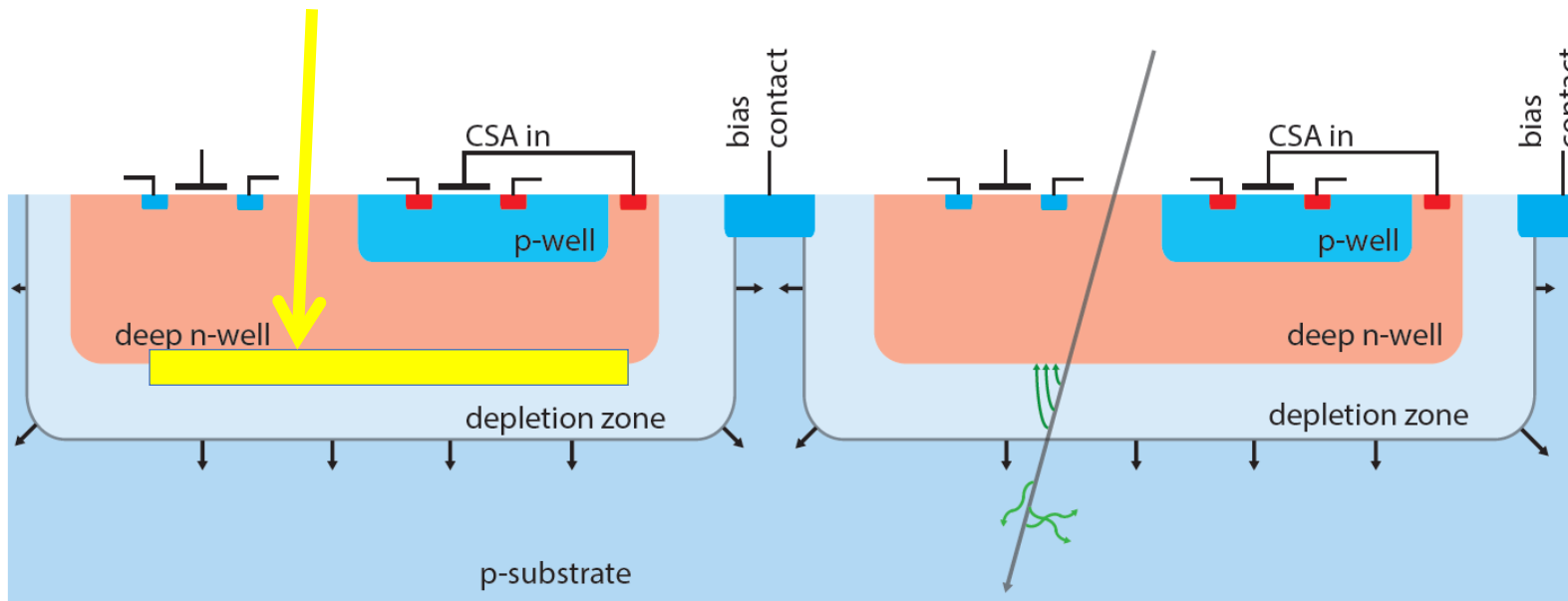
- Services integrated into carbon fiber structures



Modify HVCMOS/MAPS design to increase timing resolution

- incorporate amplification region characteristic of the LGAD sensors
- Manipulate geometries: thinner sensors, collection wells, applied bias, etc.
- 5 - 10 years to develop

Add a gain layer similar to LGAD

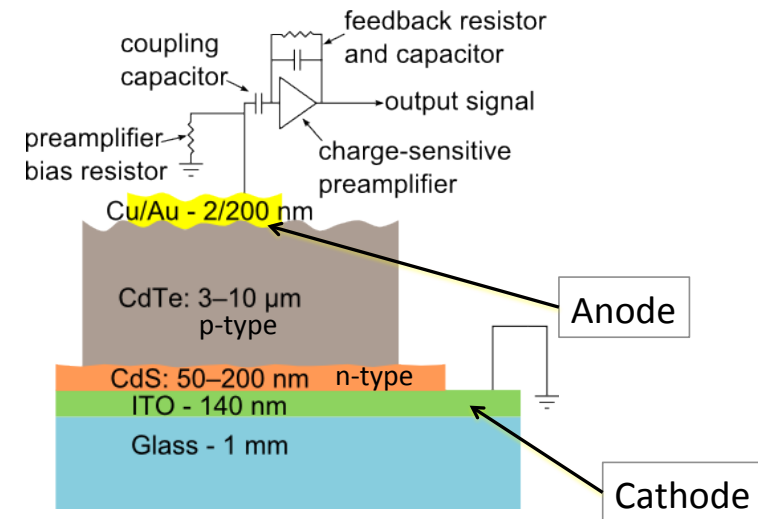
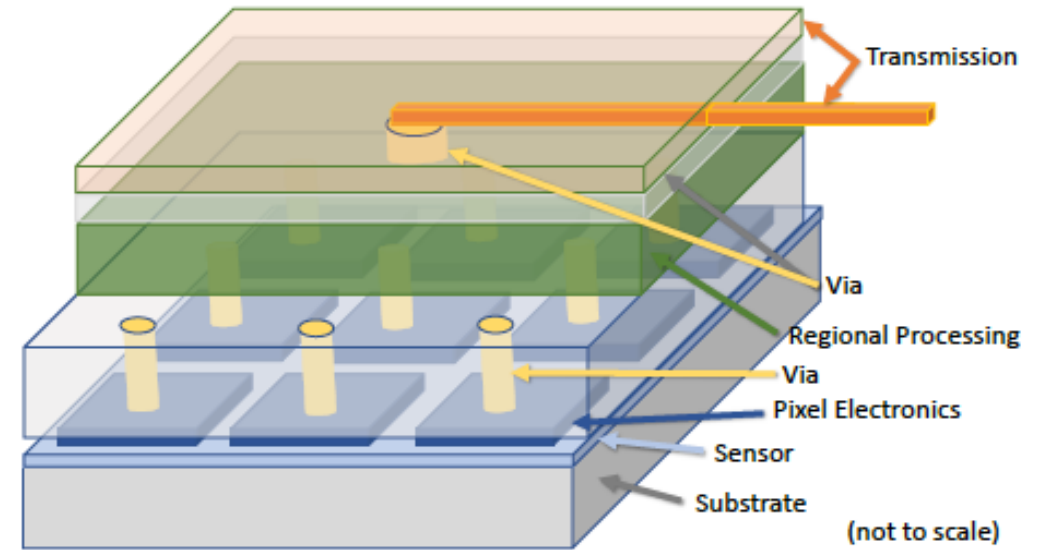
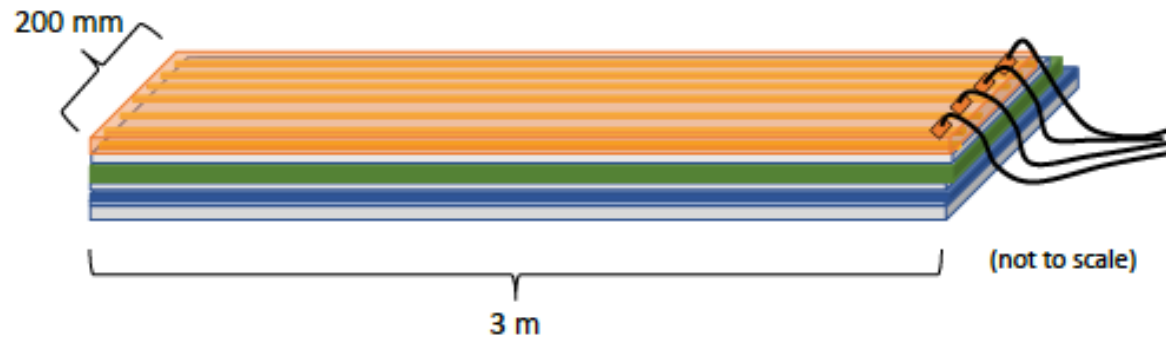
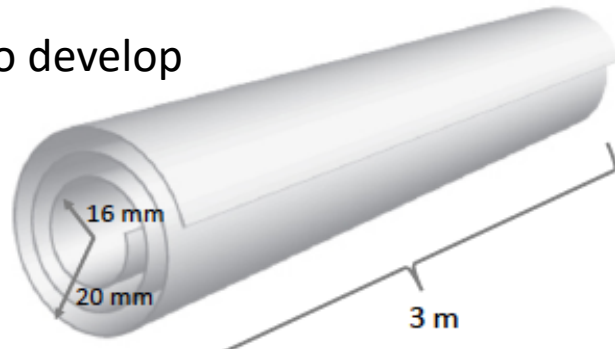


Potential Pro's:

- Low Mass
- Low power
- High position resolution
- Fast timing resolution
- Monolithic
- Radiation Tolerance
- Energy resolution
- Energy range: signal/noise
  - Low electron energies
- Low cost
- ~3 month fabrication
- Reduced cost?

# Thin Film Detectors

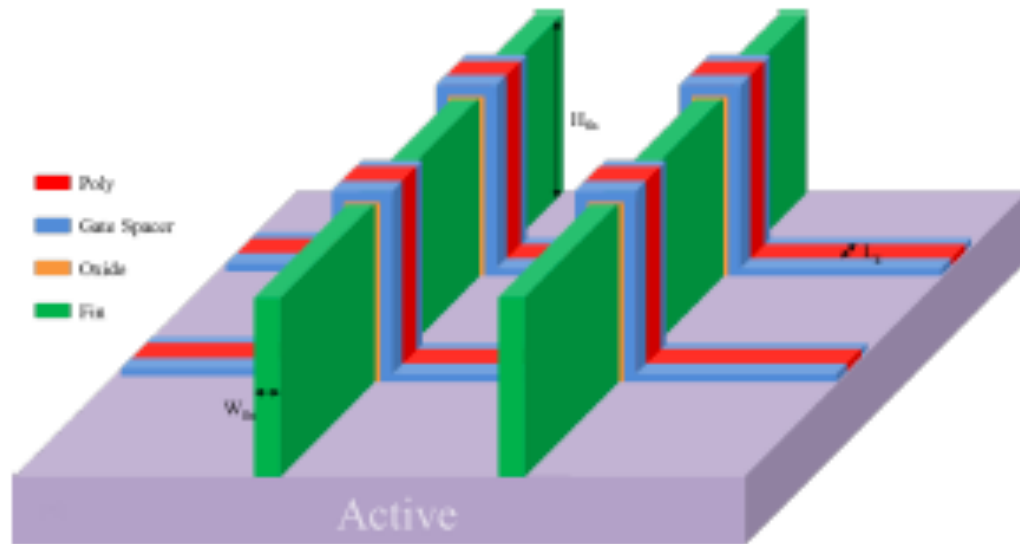
- Consider thin film deposition techniques
  - Potential to be large area low cost like LCD screens
- Options for many different semi-conductor materials
- Potential for monolithic integration of sensor + electronics
- Possible flexible substrates
- $< 1\% X/X_0$
- 10 – 20 years to develop





- FinFETs
  - ~30% less power than CMOS
  - Faster switching times
  - Energy harvesting interfaces
    - 'self-powering'
    - Can we take advantage?

## FinFETs

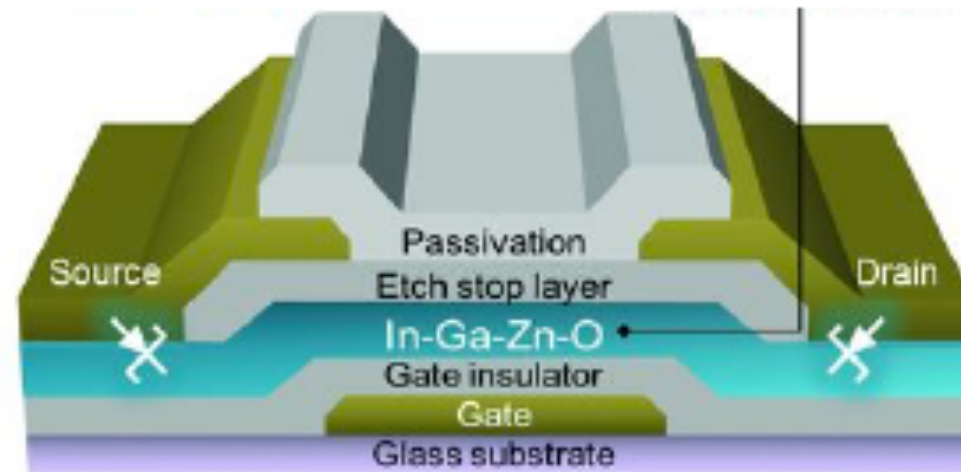


Katrine Lundager, Behzad Zeinali, Mohammad Tohidi, Jens K. Madsen, and Farshad Moradi. Low Power Design for Future Wearable and Implantable Devices. *J. Low Power Electron. Appl.*, 6(64):20, 2016.

8/13/20

- TFTs
  - High gains > 400
  - Low power < 1 nW
  - Potential integration in thin film detector

## Thin Film Transistors (TFTs)



Sungsik Lee and Arokia Nathan. Subthreshold Schottky-barrier thin-film transistors with ultralow power and high intrinsic gain. *Science*, 354(6310):302-304, 2016.

- Trend toward larger area, more channels, fast timing, etc.
- Indication that we can combine many of the best features into one technology
- Cost should also be considered
- My favorite blue sky technologies:
  - Monolithic LGAD
  - Thin Film Detector
  - Extreme low power electronics